

# GP1S25

## Side Lead Type Ultra-compact Photointerrupter

### ■ Features

1. Side lead ultra-compact transmission type
2. Conforming to solder reflow

Pre-heat : 160 °C, MAX. 120 sec

Reflow : ( 200 °C, MAX. 60 sec )  
( 240 °C, MAX. 10 sec )

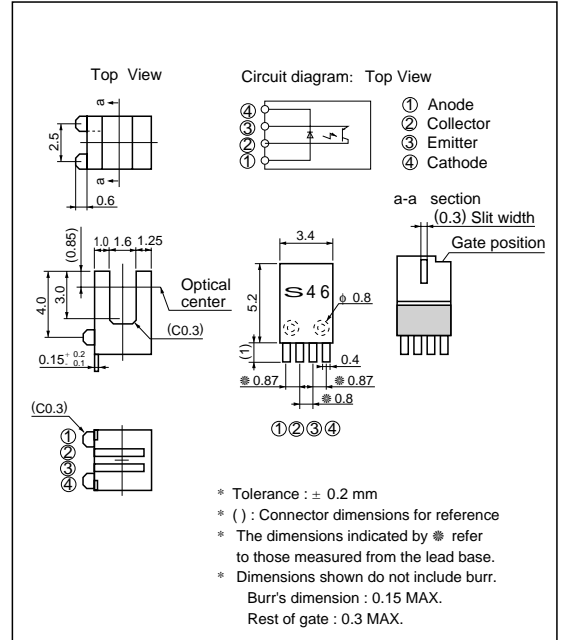
3. Slit : 0.3 mm
4. Gap : 1.6 mm

### ■ Applications

1. CD-ROM drives
2. FDDs

### ■ Outline Dimensions

(Unit : mm)



### ■ Absolute Maximum Ratings

(Ta=25°C)

| Parameter                |                             | Symbol           | Rating        | Unit |
|--------------------------|-----------------------------|------------------|---------------|------|
| Input                    | Forward current             | I <sub>F</sub>   | 50            | mA   |
|                          | Reverse voltage             | V <sub>R</sub>   | 6             | V    |
|                          | Power dissipation           | P                | 75            | mW   |
| Output                   | Collector-emitter voltage   | V <sub>CEO</sub> | 35            | V    |
|                          | Emitter-collector voltage   | V <sub>ECO</sub> | 6             | V    |
|                          | Collector current           | I <sub>C</sub>   | 20            | mA   |
|                          | Collector power dissipation | P <sub>C</sub>   | 75            | mW   |
| Total power dissipation  |                             | P <sub>tot</sub> | 100           | mW   |
| Operating temperature    |                             | T <sub>opr</sub> | - 25 to + 85  | °C   |
| Storage temperature      |                             | T <sub>stg</sub> | - 40 to + 100 | °C   |
| *1 Soldering temperature |                             | T <sub>sol</sub> | 260           | °C   |

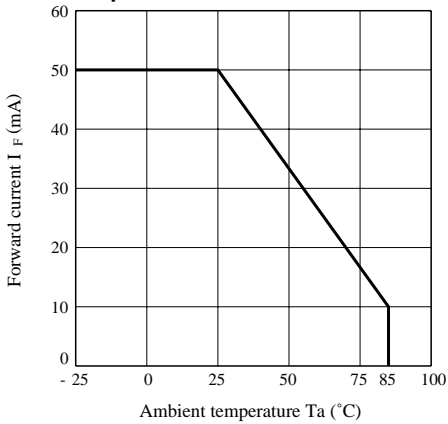
\*1 Soldering time : For 3 seconds (hand soldering)

■ **Electro-optical Characteristics**

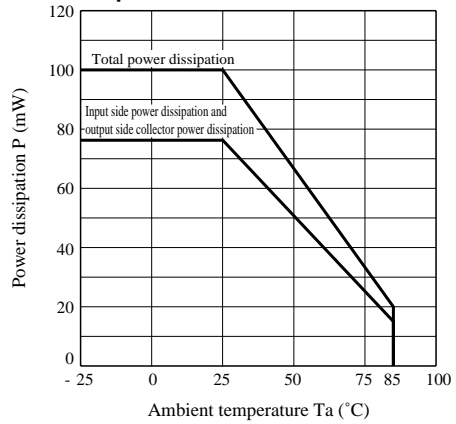
(Ta=25 °C)

| Parameter                |                                      | Symbol        | Conditions                               | MIN.                                       | TYP. | MAX. | Unit          |               |
|--------------------------|--------------------------------------|---------------|--|--|------|------|---------------|---------------|
| Input                    | Forward voltage                      | $V_F$         | $I_F = 20\text{mA}$                      | -  | 1.2  | 1.4  | V             |               |
|                          | Reverse current                      | $I_R$         | $V_R = 3\text{V}$                        | -  | -    | 10   | $\mu\text{A}$ |               |
| Output                   | Dark current                         | $I_{CEO}$     | $V_{CE} = 20\text{V}$                    | -  | -    | 100  | nA            |               |
| Transfer characteristics | Collector current                    | $I_C$         | $V_{CE} = 5\text{V}, I_F = 5\text{mA}$   | 50   | -    | 300  | $\mu\text{A}$ |               |
|                          | Collector-emitter saturation voltage | $V_{CE(sat)}$ | $I_F = 10\text{mA}, I_C = 50\mu\text{A}$ | -  | -    | 0.4  | V             |               |
|                          | Response time                        | Rise time     | $t_r$                                    | $V_{CE} = 5\text{V}, I_C = 100\mu\text{A}$ | -    | 35   | 100           | $\mu\text{s}$ |
|                          |                                      | Fall time     | $t_f$                                    | $R_L = 1\ 000\ \Omega$                     | -    | 35   | 100           | $\mu\text{s}$ |

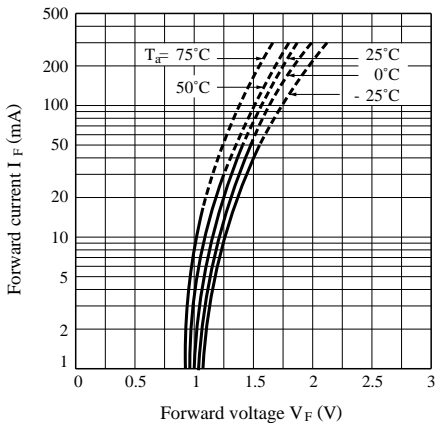
**Fig. 1 Forward Current vs. Ambient Temperature**



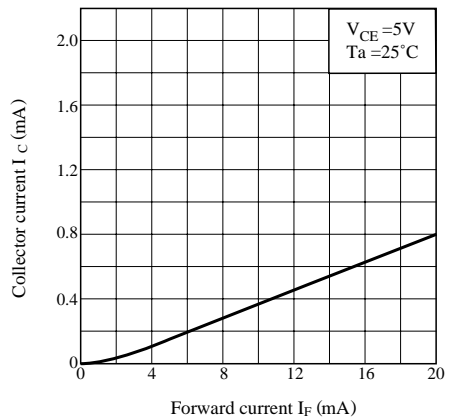
**Fig. 2 Power dissipation vs. Ambient Temperature**



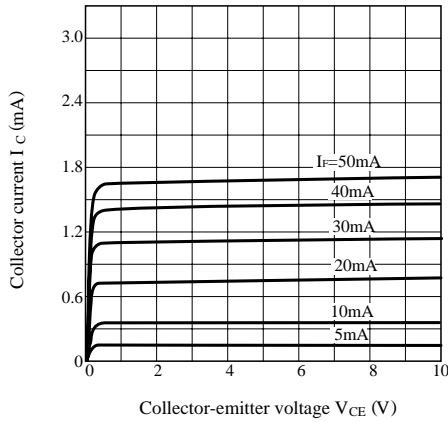
**Fig. 3 Forward Current vs. Forward Voltage**



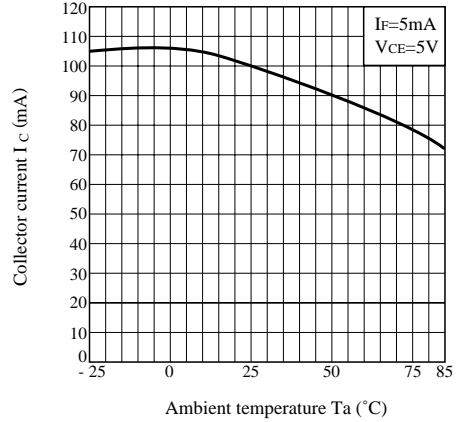
**Fig. 4 Collector Current vs. Forward Current**



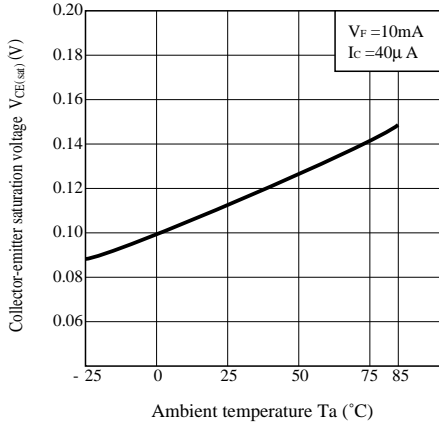
**Fig. 5 Collector Current vs. Collector-emitter Voltage**



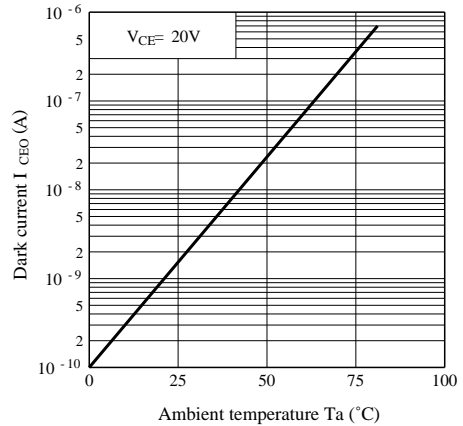
**Fig. 6 Relative Collector Current vs. Ambient Temperature**



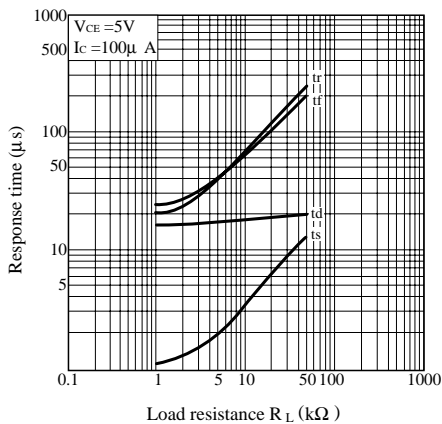
**Fig. 7 Collector-emitter Saturation Voltage vs. Ambient Temperature**



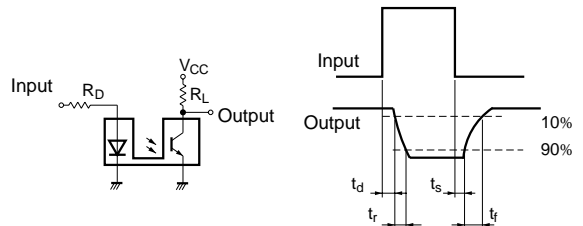
**Fig. 8 Dark Current vs. Ambient Temperature**



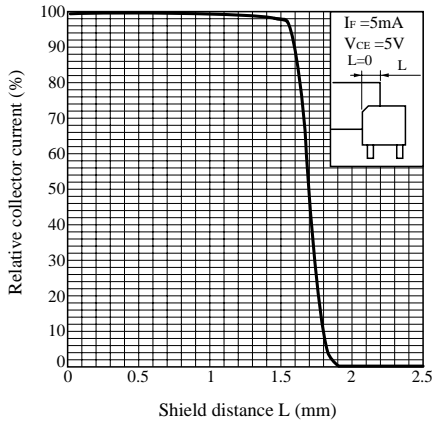
**Fig. 9 Response Time vs. Load Resistance**



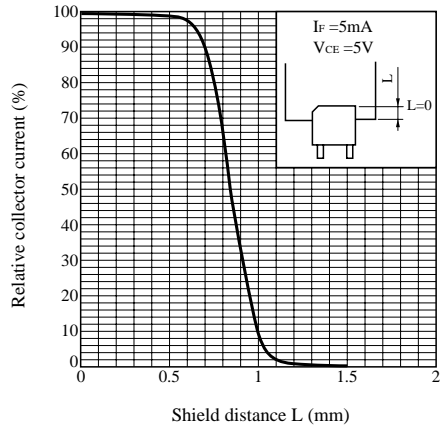
**Test Circuit for Response Time**



**Fig. 10 Detecting Position Characteristics (1)**



**Fig. 11 Detecting Position Characteristics (2)**



● Please refer to the chapter "Precautions for Use".